Тур	Hits	Search Text	DBs	Time Stamp	Comment
1 BRS	25 55 8	(high with dielectric) and (aluminum or Al) and (zirconium or Zr) and (hafnium or Hf)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/2 1 14:11	
2 BRS	1769	((high with dielectric) and (aluminum or Al) and (zirconium or Zr) and (hafnium or Hf)) and nitrid\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/1 8 12:49	
3 BRS	1521	(((high with dielectric) and (aluminum or Al) and (zirconium or Zr) and (hafnium or Hf)) and nitrid\$5) and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/1 8 12:49	
4 BRS	1314	((((high with dielectric) and (aluminum or A1) and (zirconium or Zr) and (hafnium or Hf)) and nitrid\$5) and semiconductor) and (dielectric with layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/1 8 13:00	

	Тур	Hits	Search	DBs	Time Stamp	Comment
Œ	BRS	134	(((((high with dielectric) and (aluminum or Al) and (zirconium or Zr) and (hafnium or Hf)) and nitrid\$5) and semiconductor) and (dielectric with layer)) and (composite with dielectric)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/1 8 16:37)6/1 37
0	BRS	6	<pre>(nitridation with (zirconium adj oxide)) and (high with dielectric)</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/	2004/06/1 3 14:35
7	IS& R	├ ─ 〉		USPAT	2004 8 16)4/06/1 6:37
œ	BRS	8778	438/183,197,199,216,21 7,229-231,240,257,261- 263,266,287,584,591,59 2,761,770,785,787.ccls	USPAT; US-PGPUB	2004	2004/06/2 L 14:15
0	BRS	348	438/183,197,199,216,21 7,229-231,240,257,261- 263,266,287,584,591,59 2,761,770,785,787.ccls . and (high-K with dielectric)	USPAT; US-PGPUB	2004	2004/06/2

06/21/2004, EAST Version: 1.4.1

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